TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74HC20AP, TC74HC20AF

#### **Dual 4-Input NAND Gate**

The TC74HC20A is a high speed CMOS 4-INPUT NAND GATE fabricated with silicon gate  $\rm C^2MOS$  technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

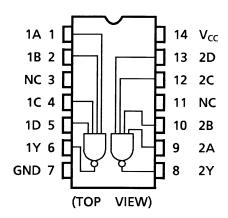
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

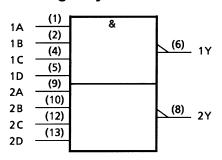
#### **Features**

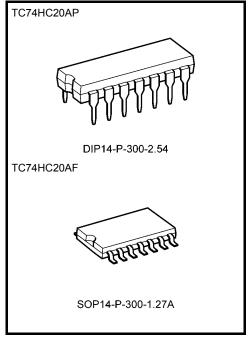
- High speed:  $t_{pd} = 8 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 1 \mu A \text{ (max)}$  at  $T_{a} = 25 \text{°C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2 to 6 V
- Pin and function compatible with 74LS20

#### **Pin Assignment**



#### **IEC Logic Symbol**





Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.)

Start of commercial production 1987-10

#### **Truth Table**

| Α | В | С | D | Υ |
|---|---|---|---|---|
| L | Х | Х | Х | Н |
| Х | L | X | X | Η |
| Х | X | Ш | X | Η |
| Х | Х | Х | L | Н |
| Н | Н | Н | Н | L |

X: Don't care

#### **Absolute Maximum Ratings (Note 1)**

| Characteristics                    | Symbol           | Rating                        | Unit |
|------------------------------------|------------------|-------------------------------|------|
| Supply voltage range               | V <sub>CC</sub>  | –0.5 to 7                     | V    |
| DC input voltage                   | V <sub>IN</sub>  | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| DC output voltage                  | V <sub>OUT</sub> | −0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current                | I <sub>IK</sub>  | ±20                           | mA   |
| Output diode current               | lok              | ±20                           | mA   |
| DC output current                  | lout             | ±25                           | mA   |
| DC V <sub>CC</sub> /ground current | Icc              | ±50                           | mA   |
| Power dissipation                  | PD               | 500 (DIP) (Note 2)/180 (SOP)  | mW   |
| Storage temperature                | T <sub>stg</sub> | –65 to 150                    | °C   |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

#### **Operating Ranges (Note)**

| Characteristics          | Symbol           | Rating                              | Unit |
|--------------------------|------------------|-------------------------------------|------|
| Supply voltage           | V <sub>CC</sub>  | 2 to 6                              | V    |
| Input voltage            | V <sub>IN</sub>  | 0 to V <sub>CC</sub>                | V    |
| Output voltage           | V <sub>OUT</sub> | 0 to V <sub>CC</sub>                | V    |
| Operating temperature    | T <sub>opr</sub> | -40 to 85                           | °C   |
|                          |                  | 0 to 1000 (V <sub>CC</sub> = 2.0 V) |      |
| Input rise and fall time | $t_r$ , $t_f$    | 0 to 500 (V <sub>CC</sub> = 4.5 V)  | ns   |
|                          |                  | 0 to 400 (V <sub>CC</sub> = 6.0 V)  |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V<sub>CC</sub> or GND.



### **Electrical Characteristics**

#### **DC Characteristics**

| Characteristics           | Symbol          | Symbol Test Condition                                |                            |                     | Ta = 25°C |      |      | Ta =<br>-40 to 85°C |      | Unit |
|---------------------------|-----------------|--|----------------------------|---------------------|-----------|------|------|---------------------|------|------|
|                           | ,               |  |                            | V <sub>CC</sub> (V) | Min       | Тур. | Max  | Min                 | Max  |      |
|                           |                 | _  |                            | 2.0                 | 1.50      | _    | _    | 1.50                | _    |      |
| High-level input voltage  | V <sub>IH</sub> |  |                            | 4.5                 | 3.15      | _    | _    | 3.15                | _    | V    |
| Ţ.                        |                 |  |                            | 6.0                 | 4.20      | _    | —    | 4.20                | —    |      |
|                           |                 |  |                            | 2.0                 | _         | _    | 0.50 | _                   | 0.50 |      |
| Low-level input voltage   | $V_{IL}$        | _  |                            | 4.5                 | _         | _    | 1.35 | _                   | 1.35 | V    |
| ŭ                         |                 |  | _                          | 6.0                 |           |      | 1.80 | _                   | 1.80 |      |
|                           | Voн             | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> |                            | 2.0                 | 1.9       | 2.0  | _    | 1.9                 | _    |      |
|                           |                 |  | $I_{OH} = -20 \mu A$       | 4.5                 | 4.4       | 4.5  | _    | 4.4                 | _    |      |
| High-level output voltage |                 |  |                            | 6.0                 | 5.9       | 6.0  | _    | 5.9                 | _    | V    |
| Ü                         |                 |  | I <sub>OH</sub> = -4 mA    | 4.5                 | 4.18      | 4.31 | _    | 4.13                | _    |      |
|                           |                 |  | $I_{OH} = -5.2 \text{ mA}$ | 6.0                 | 5.68      | 5.80 | _    | 5.63                | _    |      |
|                           | V <sub>OL</sub> | $V_{IN} = V_{IH}$                                    |                            | 2.0                 | _         | 0.0  | 0.1  | _                   | 0.1  |      |
|                           |                 |  | $I_{OL} = 20 \mu A$        | 4.5                 | _         | 0.0  | 0.1  | _                   | 0.1  |      |
| Low-level output voltage  |                 |  |                            | 6.0                 | _         | 0.0  | 0.1  | _                   | 0.1  | V    |
| Ü                         |                 |  | I <sub>OL</sub> = 4 mA     | 4.5                 | _         | 0.17 | 0.26 | _                   | 0.33 |      |
|                           |                 |  | $I_{OL} = 5.2 \text{ mA}$  | 6.0                 | _         | 0.18 | 0.26 | _                   | 0.33 |      |
| Input leakage current     | I <sub>IN</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND             |                            | 6.0                 |           | _    | ±0.1 | _                   | ±1.0 | μА   |
| Quiescent supply current  | Icc             | V <sub>IN</sub> = V <sub>CC</sub> or GND             |                            | 6.0                 | _         | _    | 1.0  | _                   | 10.0 | μА   |

### AC Characteristics ( $C_L = 15 \text{ pF}$ , $V_{CC} = 5 \text{ V}$ , $Ta = 25^{\circ}\text{C}$ , input: $t_r = t_f = 6 \text{ ns}$ )

| Characteristics        | Symbol           | Test Condition |  | Тур. | Max | Unit |
|------------------------|------------------|----------------|--|------|-----|------|
| Output transition time | tTLH             | _              |  | 5    | 8   | ns   |
| Output transition time | t <sub>THL</sub> | _              |  |      |     |      |
| Propagation delay time | t <sub>pLH</sub> | _              |  | 8    | 15  | ns   |
| Tropagation delay time | t <sub>pHL</sub> |                |  | J    | 1.5 | 110  |

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### AC Characteristics ( $C_L = 50$ pF, input: $t_r = t_f = 6$ ns)

| Characteristics               | Symbol                 | Test Condition |                     | Ta = 25°C |      |     | Ta =<br>-40 to 85°C |     | Unit |
|-------------------------------|------------------------|----------------|---------------------|-----------|------|-----|---------------------|-----|------|
|                               |                        |                | V <sub>CC</sub> (V) | Min       | Тур. | Max | Min                 | Max |      |
|                               | <b>4</b> —             |                | 2.0                 | _         | 30   | 75  | _                   | 95  |      |
| Output transition time        | t <sub>TLH</sub>       | _              | 4.5                 | _         | 8    | 15  | _                   | 19  | ns   |
|                               | tTHL                   |                | 6.0                 | _         | 7    | 13  | _                   | 16  |      |
|                               | 4                      |                | 2.0                 | _         | 33   | 90  | _                   | 115 |      |
| Propagation delay time        | t <sub>pLH</sub>       | _              | 4.5                 | _         | 11   | 18  | _                   | 23  | ns   |
|                               | t <sub>pHL</sub>       |                | 6.0                 | _         | 9    | 15  | _                   | 20  |      |
| Input capacitance             | C <sub>IN</sub>        | _              |                     | _         | 5    | 10  | _                   | 10  | pF   |
| Power dissipation capacitance | C <sub>PD</sub> (Note) | _              |                     |           | 29   | _   |                     |     | pF   |

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

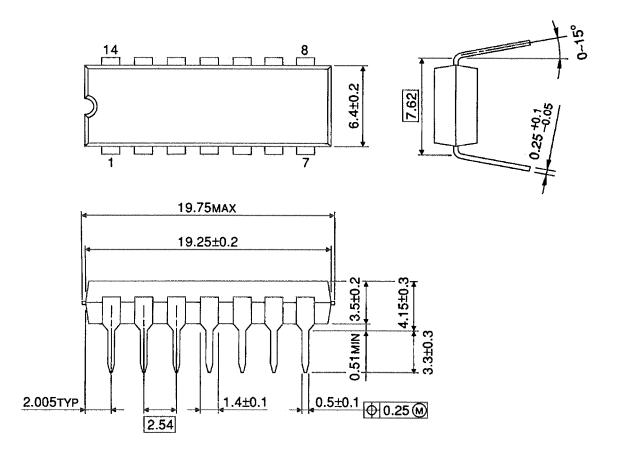
$$I_{CC}$$
 (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$  (per gate)

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### **Package Dimensions**

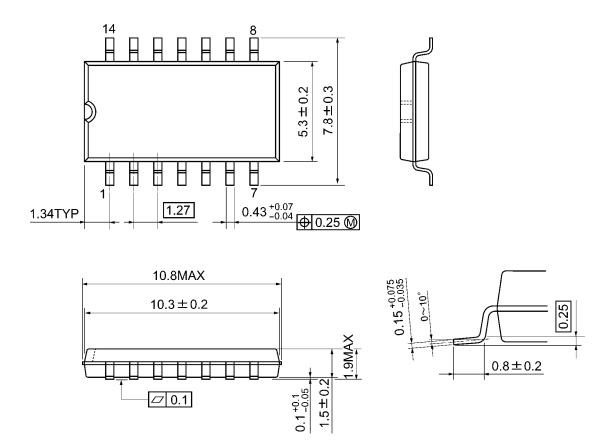
DIP14-P-300-2.54 Unit: mm



Weight: 0.96 g (typ.)

### **Package Dimensions**

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

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